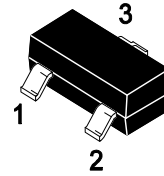




## Discription

The NUP2105LT1G protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. Excellent clamping capability, low leakage, low capacitance, and fast response time provide best in class protection on designs that are exposed to ESD.

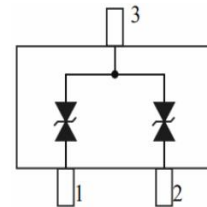
It gives designer the flexibility to protect one bi-directional line in applications where arrays are not practical.



SOT-23

## Features

- ★ Low Leakage
- ★ IEC61000-4-2 Level 4 ESD Protection
- ★ We declare that the material of product compliant with RoHS requirements and Halogen Free.
- ★ S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



Circuit Diagram

## Ordering information

| Product ID  | Pack   | Qty(PCS) |
|-------------|--------|----------|
| NUP2105LT1G | SOT-23 | 3000     |

## MAXIMUM RATINGS

| Rating                                 | Symbol            | Value      | Unit |
|--|-------------------|------------|------|
| IEC 61000-4-2 (ESD)                    | Air discharge     | ±30        | kV   |
|  | Contact discharge | ±30        | kV   |
| Junction and Storage Temperature Range | TJ,TSTG           | -55 to 150 | °C   |

Stresses exceeding Maximum Ratings may damage the device. Maximum Rating are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

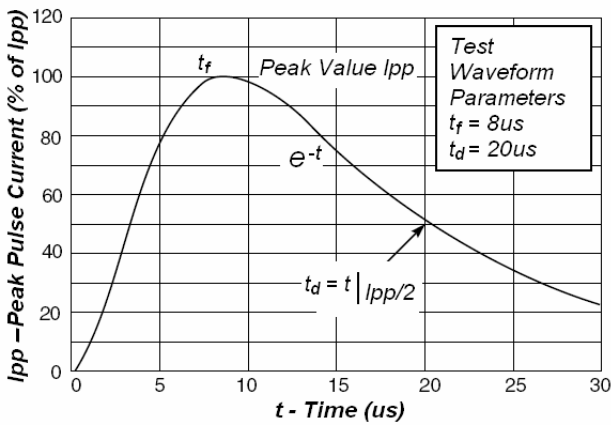


**ELECTRICAL CHARACTERISTICS**

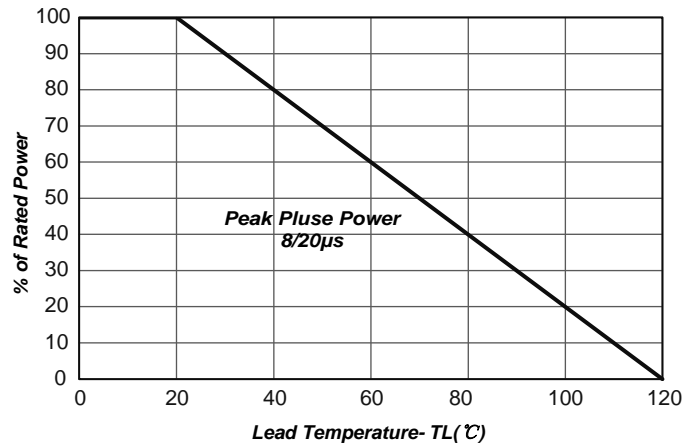
| Device      | $V_{RWM}$ (V) | $I_R$ ( $\mu$ A) @ $V_{RWM}$ | $V_{BR}$ (V) @ $I_T$ (Note 1) |     | $I_T$ | $V_C$ (V) @ MAX $I_{PP}$ (Note 2) | $I_{PP}$ (A) (Note 2) | $P_{PK}$ (W) (Note 2) | C (pF) |
|-------------|---------------|------------------------------|-------------------------------|-----|-------|-----------------------------------|-----------------------|-----------------------|--------|
|             | Max           | Max                          | Min                           | Max | mA    | Max                               | Max                   | Max                   | Typ    |
| NUP2105LT1G | 24            | 0.5                          | 26                            | 33  | 1     | 40                                | 4                     | 160                   | 10     |

Other voltage available upon request.

1.  $V_{BR}$  is measured with a pulse test current  $I_T$  at an ambient temperature of 25°C
2. Surge current waveform per Figure 1.



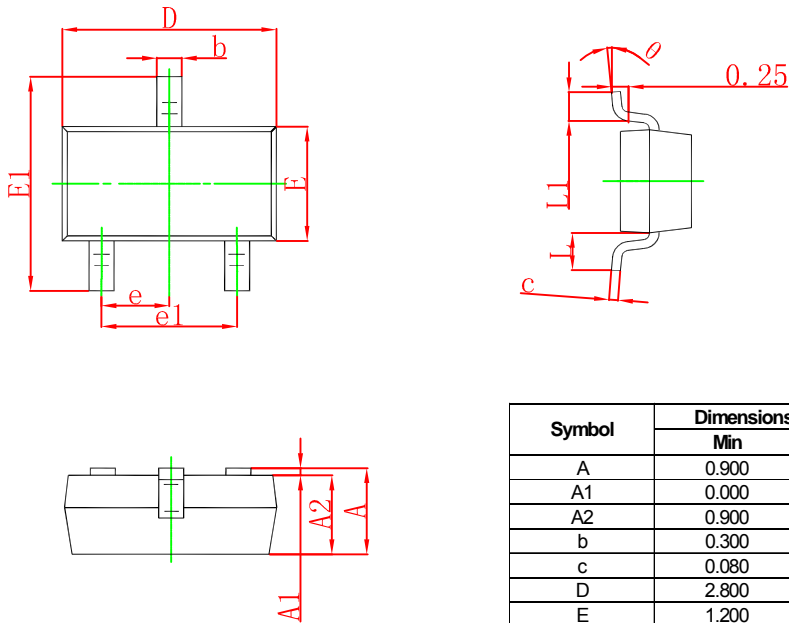
**Fig1. Pulse Waveform**



**Fig2.Power Derating Curve**

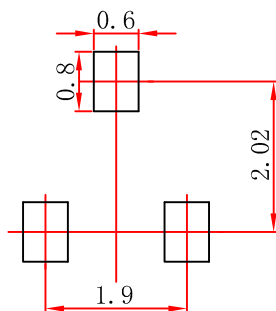


### SOT-23 Package Outline Dimensions



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min                       | Max   | Min                  | Max   |
| A      | 0.900                     | 1.150 | 0.035                | 0.045 |
| A1     | 0.000                     | 0.100 | 0.000                | 0.004 |
| A2     | 0.900                     | 1.050 | 0.035                | 0.041 |
| b      | 0.300                     | 0.500 | 0.012                | 0.020 |
| c      | 0.080                     | 0.150 | 0.003                | 0.006 |
| D      | 2.800                     | 3.000 | 0.110                | 0.118 |
| E      | 1.200                     | 1.400 | 0.047                | 0.055 |
| E1     | 2.250                     | 2.550 | 0.089                | 0.100 |
| e      | 0.950 TYP                 |       | 0.037 TYP            |       |
| e1     | 1.800                     | 2.000 | 0.071                | 0.079 |
| L      | 0.550 REF                 |       | 0.022 REF            |       |
| L1     | 0.300                     | 0.500 | 0.012                | 0.020 |
| θ      | 0°                        | 8°    | 0°                   | 8°    |

### SOT-23 Suggested Pad Layout



Note:  
 1. Controlling dimension: in millimeters.  
 2. General tolerance:  $\pm 0.05\text{mm}$ .  
 3. The pad layout is for reference purposes only.



### Attention

- Any and all HUA XUAN YANG ELECTRONICS products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your HUA XUAN YANG ELECTRONICS representative nearest you before using any HUA XUAN YANG ELECTRONICS products described or contained herein in such applications.
- HUA XUAN YANG ELECTRONICS assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein.
- Specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- HUA XUAN YANG ELECTRONICS CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all HUA XUAN YANG ELECTRONICS products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of HUA XUAN YANG ELECTRONICS CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. HUA XUAN YANG ELECTRONICS believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the HUA XUAN YANG ELECTRONICS product that you intend to use.

单击下面可查看定价，库存，交付和生命周期等信息

[>>HXY MOSFET\(华轩阳电子\)](#)